NSN 5961-00-050-3463

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Inclosure Material:

Metal

Overall Length:

0.672 inches

Overall Diameter:

0.505 inches

Mounting Facility Quantity:

1

Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

Internal Junction Configuration:

Npn

Mounting Method:

Threaded stud

Features Provided:

Hermetically sealed case

Overall Width Across Flats:

0.430 inches

Thread Size:

0.190 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

25.0 breakdown voltage, collector-to-base, emitter open

Current Rating Per Characteristic:

1.00 amperes collector current, dc

Power Rating Per Characteristic:

30.0 watts small-signal input power, common-collector

Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius ambient air

Thread Series Designator:

Unf

Terminal Type And Quantity:

3 tab, solder lug

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

No

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